Voltage-dependent gating mechanisms of large conductance Ca\(^{2+}\) and voltage-activated (BK) channels were investigated using two-dimensional maximum likelihood analysis of single-channel open and closed intervals. To obtain sufficient data at negative as well as positive voltages, single-channel currents were recorded at saturating Ca\(^{2+}\) from BK channels mutated to remove the RCK1 Ca\(^{2+}\) and Mg\(^{2+}\) sensors. The saturating Ca\(^{2+}\) acting on the Ca\(^{2+}\) bowl sensors of the resulting BK\(_{6}\) channels increased channel activity while driving the gating into a reduced number of states, simplifying the model. Five highly constrained idealized gating mechanisms based on extensions of the Monod-Wyman-Changeux model for allosteric proteins were examined. A 10-state model without coupling between the voltage sensors and the opening/closing transitions partially described the voltage dependence of Po but not the single-channel kinetics. With allowed coupling, the model gave improved descriptions of Po and approximated the single-channel kinetics; each activated voltage sensor increased the opening rate approximately an additional 2.5-fold while having little effect on the closing rate. Allowing cooperativity among voltage sensors further improved the description of the data: each activated voltage sensor increased the activation rate of the remaining voltage sensors approximately fourfold, with little effect on the deactivation rate. The coupling factor was decreased in models with cooperativity from ~2.5 to ~1.8. Whether the apparent cooperativity among voltage sensors arises from imposing highly idealized models or from actual cooperativity will require additional studies to resolve. For both cooperative and noncooperative models, allowing transitions to five additional brief (flicker) closed states further improved the description of the data. These observations show that the voltage-dependent single-channel kinetics of BK\(_{6}\) channels can be approximated by highly idealized allosteric models in which voltage sensor movement increases Po mainly through an increase in channel opening rates, with limited effects on closing rates.
Cui and Aldrich, 2000; Ma et al., 2006; Savalli et al., 2006). To a first approximation, the voltage sensors and high affinity Ca\textsuperscript{2+} sensors of BK channels function independently but synergistically to activate the channels (Cui and Aldrich, 2000; Rothberg and Magleby, 2000; Horrigan and Aldrich, 2002).

Extensive studies have shown that the voltage and high affinity Ca\textsuperscript{2+}-dependent gating of BK channels is consistent with a minimal two-tiered 50-state model with 25 closed states on the upper tier and 25 open states on the lower tier. The gating mechanisms developed in these previous studies are generally consistent with the macroscopic ionic and gating currents (Horrigan and Aldrich, 1999, 2002; Horrigan et al., 1999; Cui and Aldrich, 2000) and the single-channel kinetics (Rothberg and Magleby, 1998, 1999, 2000) over wide ranges of voltage and Ca\textsuperscript{2+}. Although these studies have proven highly useful toward understanding gating, there are still many unanswered questions. Both the macro current and single-channel studies assumed one high affinity Ca\textsuperscript{2+} binding site per subunit rather than the two known high affinity sites. The macro current studies typically focused on equilibrium constants rather than rate constants, so it is not necessarily clear whether it is the forward or backward (or both) rate constants that are altered by voltage and Ca\textsuperscript{2+}. The single-channel studies used models with limited numbers of states compared with the 50-state model, so it can be difficult to associate specific transitions in the simplified models with those in the 50-state model. Because all parameters were typically free in the models with limited numbers of states, it can be difficult to interpret the findings in terms of a consistent underlying structural mechanism.

Our present study addresses some of these questions for the voltage-dependent gating of BK channels. Single-channel recording and kinetic analysis is used to facilitate the determination of rate constants. Highly constrained models based on extensions of the Monod-Wyman-Changeux (MWC) model (Marks and Jones, 1992; Ríos et al., 1993; McCormack et al., 1994; Horrigan et al., 1999; Horrigan and Aldrich, 2002) are examined so that the data can be interpreted in terms of allosteric models based on the known quaternary structural features of BK channels. The determined rate constants allow the allosteric factors to be determined separately for forward and backward transitions. To activate the channel sufficiently (but not too much) so that single-channel data could be obtained over a wide range of negative and positive membrane potentials, the Mg\textsuperscript{2+} and RCK1 Ca\textsuperscript{2+} sensors were removed, leaving one Ca\textsuperscript{2+} bowl sensor on each subunit. Applying saturating Ca\textsuperscript{2+}, then increased the activity sufficiently to obtain the required data and also forced the gating into mainly 10 of the 50 states, greatly simplifying the models and the determination of gating parameters.

We found for highly idealized 10-state two-tiered models and also for 15-state three-tiered models with a row of flicker states that the voltage sensors act mainly by decreasing the energy barrier for channel opening with little effect on the energy barrier for channel closing. Each additional activated voltage sensor increased the opening rate approximately an additional 23-fold while having little effect on the closing rate. In addition, we found that allowing cooperativity among the voltage sensors in these highly idealized models further improved the description of the gating, with each additional activated voltage sensor increasing the activation rate of the deactivated voltage sensors approximately fourfold. Whether this apparent cooperativity arises from imposing highly idealized models or represents actual cooperativity will require additional studies to resolve. The highly idealized gating mechanisms could describe the single-channel kinetics over wide ranges of voltage and will provide tools to relate kinetics to underlying structure.

**MATERIALS AND METHODS**

Clones, mutagenesis, and channel expression

Experiments were performed using the mouse Slo1 α subunit of the BK channel (Butler et al., 1993) as modified by Xia et al. (2002) to disable the RCK1 high affinity Ca\textsuperscript{2+} sensor (D362A/D367A) and the low affinity Ca\textsuperscript{2+}/Mg\textsuperscript{2+} sensor (E399A), leaving the Ca\textsuperscript{2+} bowl sensor. The channels were transiently expressed in HEK293 cells together with green fluorescent protein to identify transfected cells as described previously (Nimigean and Magleby, 1999). In a few experiments, when specifically indicated, the mutated channels were expressed in *Xenopus laevis* oocytes after injection of cRNA as described previously (Qian et al., 2006).

Electrophysiology and solutions

Single-channel currents were recorded from excised inside-out patches of membrane using Axopatch 200A or 200B amplifiers (Molecular Devices). Data were obtained from patches containing a single channel, which was verified by increasing Po to >0.5 and observing a single open current level for extended periods of recording. The pipette solution contained 150 mM KCl and 5 mM TES buffer. The solution at the intracellular side of the excised patches of membrane contained 150 mM KCl, 5 mM TES, 1 mM EGTA, and 1 mM HEDTA. In addition, 50 µM 8-crown ether ((+)-18-Crown-6)-2,3,11,12-tetraacarboxylic acid was included in the intracellular solution in most experiments to bind contaminants such as Ca\textsuperscript{2+} to prevent occasional long channel blocks (Diaz et al., 1996). Sufficient (±)-18-Crown-6 was also included in the extracellular solution to keep free Ca\textsuperscript{2+} below 0.10 M, 18-crown ether also binds K\textsuperscript{+} (3.3 × 10\textsuperscript{-5} M) and Ca\textsuperscript{2+} (108 M; Diaz et al., 1996). Sufficient Ca\textsuperscript{2+} was added to the solutions to obtain free Ca\textsuperscript{2+} of either 95 or 283 µM, as calculated with an in-house buffer program. Unless indicated otherwise, experiments were performed with 95 µM intracellular free (Ca\textsuperscript{2+}), Solutions were adjusted to pH 7.0. Recordings were made at room temperature (22–25°C).

Estimating rate constants and gating parameters for kinetic models

The methods for using 50% threshold analysis to measure open- and closed-interval durations, identifying stable single-channel data with stability plots, plotting 1-D and 2-D dwell-time...
dwell-time distributions, applying maximum likelihood methods to describe 1-D dwell-time distributions with sums of exponentials, and estimating the most likely rate constants and gating parameters from simultaneous (global) maximum likelihood fitting of 2-D dwell-time distributions obtained over a range of experimental conditions (in this case voltage) have been described in detail previously (McManus and Magleby, 1988; Rothberg and Magleby, 2000; Gil et al., 2001). Missed events were taken into account when estimating the gating parameters using the method described by Crouzy and Sigworth (1990).

Ranking kinetic models

Two methods were used to rank the different kinetic schemes: the likelihood ratio test and the Schwarz criterion (SC). The likelihood ratio test applies to nested models and provides both a ranking and a significance for the ranking (Horn and Lange, 1983). The models examined in this study are nested because the simpler schemes are contained in the more complex schemes. The SC (also referred to as the Schwarz information criterion or the Bayesian information criterion) applies to both nested and nonnested models and provides ranking but not the significance of the ranking (Koehler and Murphy, 1988).

Adding additional free gating parameters to a model typically increases the likelihood of the fit. To determine whether the fit is significantly better using the likelihood ratio test, the models were compared by determining the LLR from LLR = LLk − LLk−1, where LLR is the natural logarithm of the ratio of the maximum likelihoods for k versus k-1 free parameters, and LLk and LLk−1 are the natural logarithms of the maximum likelihoods that the experimental data were drawn from the 2-D dwell-time distributions predicted by the models with the indicated number of free parameters. Twice the value of LLR is distributed as \( \chi^2 \) with the degrees of freedom equal to \( n \), the difference in the number of free parameters. For example, a model with two additional free parameters is judged significantly better (\( P < 0.05 \) when the LLR is >2.996, as two times this value is 5.99, the \( \chi^2 \) value for two degrees of freedom at the 0.05 level (Horn and Lange, 1983). A table for determining significance with the likelihood ratio test is found in Rothberg et al. (1997). Note that the likelihood values take the natural logarithm of the maximum likelihood estimate, so that sufficient single-channel data could be obtained for analysis. Consequently, we took advantage of the synergistic activation of BK channels by voltage and Ca\(^{2+}\), specifically defined in terms of kinetic models to be used to reduce the numbers of potential states and to shift the gating into a voltage range in which the full range of open probability, \( P_o \), can be difficult to obtain sufficient single-channel data for analysis. Consequently, we took advantage of the synergistic activation of BK channels by voltage and Ca\(^{2+}\) (Barrett et al., 1982; Cui et al., 1997), using Ca\(^{2+}\) to left shift the \( P_o \) versus voltage curves so that sufficient single-channel data could be obtained over a wide range of both negative and positive potentials. To simplify the gating mechanism, the experiments were performed in saturating Ca\(^{2+}\) on modified BK channels, termed BKb channels, mutated to have a single Ca\(^{2+}\)-sensor per subunit, the Ca\(^{2+}\)-bowl. Saturating Ca\(^{2+}\) was used to drive the channel into a reduced number of states, as will be explained in a later section. A single Ca\(^{2+}\)-sensor per subunit was used to reduce the numbers of potential states and to shift the gating into a voltage range in which the full range of open probability, \( P_o \), could be studied using potentials between ±100 mV, where the membrane remains stable.

RESULTS

Single-channel analysis was used to characterize the allosteric coupling and cooperative factors involved in activation of BK channels by voltage. Coupling in this study refers to the action of the voltage sensors on altering the transition rates for opening and closing. Cooperativity refers to interactions among the voltage sensors. Coupling and cooperativity will be specifically defined in terms of kinetic models to be presented later.

BKb channels in saturating Ca\(^{2+}\), simplify the gating mechanism and shift the \( P_o \) versus voltage curve into a usable range to obtain single-channel data

Because of the extremely low activity of BK channels at negative potentials in the absence of Ca\(^{2+}\), it can be difficult to obtain sufficient single-channel data for analysis. Consequently, we took advantage of the synergistic activation of BK channels by voltage and Ca\(^{2+}\), using Ca\(^{2+}\) to left shift the \( P_o \) versus voltage curves so that sufficient single-channel data could be obtained over a wide range of both negative and positive potentials. To simplify the gating mechanism, the experiments were performed in saturating Ca\(^{2+}\) on modified BK channels, termed BKb channels, mutated to have a single Ca\(^{2+}\)-sensor per subunit, the Ca\(^{2+}\)-bowl. Saturating Ca\(^{2+}\) was used to drive the channel into a reduced number of states, as will be explained in a later section. A single Ca\(^{2+}\)-sensor per subunit was used to reduce the numbers of potential states and to shift the gating into a voltage range in which the full range of open probability, \( P_o \), could be studied using potentials between ±100 mV, where the membrane remains stable.
To construct the BKβ channels, the high affinity RCK1 Ca\(^{2+}\) sensor and the low affinity Ca\(^{2+}/Mg\(^{2+}\) sensor on each subunit were disabled with the mutations D362A/D367A and E399A, respectively (Xia et al., 2002; Zeng et al., 2005). To assure saturating activation of the remaining Ca-bowl sensors, all experiments were performed with 95 µM free Ca\(^{2+}\), which is >20-fold greater than the apparent K\(_d\) for the Ca bowl.

<table>
<thead>
<tr>
<th>Channel</th>
<th>V(_{0.5}) (mV)</th>
<th>Millivolts per e-fold change in Po(^{-})</th>
<th>(q_G) (e(_o))^3</th>
<th>(P_{0\max})</th>
</tr>
</thead>
<tbody>
<tr>
<td>DM1</td>
<td>22.9</td>
<td>13.4</td>
<td>1.90</td>
<td>0.95</td>
</tr>
<tr>
<td>DM2</td>
<td>29.0</td>
<td>12.5</td>
<td>2.04</td>
<td>0.94</td>
</tr>
<tr>
<td>DM3</td>
<td>25.0</td>
<td>9.1</td>
<td>2.80</td>
<td>0.94</td>
</tr>
<tr>
<td>DM4</td>
<td>48.0</td>
<td>10.6</td>
<td>2.41</td>
<td>0.92</td>
</tr>
<tr>
<td>Mean</td>
<td>30.7 ± 5.9</td>
<td>11.4 ± 1.0</td>
<td>2.29 ± 0.20</td>
<td>0.94 ± 0.1</td>
</tr>
</tbody>
</table>

The means ± SEM are presented in the bottom row.

\(^{a}\)The voltage sensitivity is defined as the voltage change (in millivolts) required for an e-fold change in Po.

\(^{b}\)Effective gating charge \(q_G = k_BT/(\text{millivolts per e-fold change in Po})\), where \(k_B\) is Boltzmann’s constant, \(T\) is absolute temperature, and \(k_BT = 25.5\) (millivolts e\(_o\)) at 23°C.
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Voltage dependence of the opening and closing transitions

The voltage dependence of the gating of wt BK channels, and also presumably for the mutant BKB channels because of their essentially identical voltage sensitivity to wt channels (see preceding section), reflects gating (Bao et al., 2002; Xia et al., 2002). Observations consistent with saturation of Ca-bowl sites with ~100 µM Ca\(^{2+}\) have been reported previously (Rothberg and Magleby, 1999; Bao et al., 2002; Xia et al., 2002). As a further test of saturation, we found no significant difference in Po for BK\(_B\) channels with 95 and 283 µM free Ca\(^{2+}\) at −100 mV (0.00021 ± 0.00008 vs. 0.00020 ± 0.00007, P > 0.9, n = 3–5) for experiments with single-channel recording.

Voltage dependence of BK\(_B\) channels in saturating Ca\(^{2+}\)

Single-channel currents from a BK\(_B\) channel are shown in Fig. 1 for voltages ranging from −70 to 100 mV with 95 µM of saturating free Ca\(^{2+}\). Similar to wild-type (wt) BK channels, depolarization activates BK\(_B\) channels, increasing channel activity, as indicated previously (Xia et al., 2002). The voltage-dependent increase in Po is plotted in Fig. 1 B for four BK\(_B\) channels, each studied separately in a single-channel patch. Each channel has the same general activation response, but individual channels have somewhat different values for \(V_{0.5}\), the voltage for half activation. Such variability among individual channels and even among macro currents recorded from different patches containing large numbers of channels is observed for BK channels (McManus and Magleby, 1991; Rothberg and Magleby, 1998; Horrigan and Aldrich, 2002; Niu and Magleby, 2002). Fitting the data from each channel with a single Boltzmann distribution gives the values in Table I, with a mean \(V_{0.5}\) of 30.7 ± 5.9 mV (SEM), a mean slope of 11.4 ± 1.0 mV/e-fold change in Po, an effective partial charge movement for activation of 2.29 electronic units (e\(_o\)), and a maximum Po of 0.94 ± 0.01. The voltage sensitivity (slope) for these BK\(_B\) channels agrees with that observed previously for native BK channels in cultured rat skeletal muscle of 11.1 ± 3.1 mV (Rothberg and Magleby, 2000). The effective partial charge over the voltage range of these experiments of 2.29 e\(_o\) is consistent with previous single-channel (Rothberg and Magleby, 2000), ionic (Horrigan et al., 1999; Ma et al., 2006), and gating current (Horrigan and Aldrich, 1999, 2002) studies for wt BK channels. Therefore, the mutations to disable the RCK1 Ca\(^{2+}\) sensors and the low affinity Ca\(^{2+}/\)Mg\(^{2+}\) sensors appear to have little, if any, effect on the voltage activation mechanism.

Fig. 1 (C and D) shows that the increase in Po with depolarization in BK\(_B\) channels arises from changes in both the open- and closed-interval durations. Depolarizing from −100 to 100 mV increased the mean open time ~12-fold from 0.14 to 1.7 ms and decreased mean closed time ~4,500-fold from 580 to 0.13 ms. Such depolarization-induced changes in mean open and closed intervals, with the dominant effect on the closed intervals, are also a characteristic of wt BK channels (Rothberg and Magleby, 2000).

![Figure 2. Estimating the partial charge associated with the opening and closing transitions for BK\(_B\) channels gating in saturating Ca\(^{2+}\).](https://jgp.rupress.org/article-figures/465-F2.png)

(Figure 2. Estimating the partial charge associated with the opening and closing transitions for BK\(_B\) channels gating in saturating Ca\(^{2+}\). (A) Plot of Po versus voltage. Circles plot data obtained for BK\(_B\) channels expressed in oocytes for patches with a single channel (open circles) and from two to six channels per patch (closed circles). Squares plot data obtained from macro currents from BK\(_B\) channels expressed in HEK cells. (B) Voltage dependence of mean open times at negative potentials. The line is a linear fit to open times negative to −100 mV. Projecting to 0 mV gives an intrinsic channel closing rate (\(k\) in Schemes III, IV, and V) of 6,420 ± 680 s\(^{-1}\) with a partial charge of −0.099 ± 0.015 e\(_o\) (257 mV/e-fold change). (C) Voltage dependence of mean closed times. The line is a linear fit to closed times negative to −100 mV. Projecting to 0 mV gives an estimate of the intrinsic opening rate (\(H\) in Schemes III, IV, and V) of 3.87 ± 1.88 s\(^{-1}\) with a partial charge of 0.237 ± 0.06 e\(_o\) (108 mV/e-fold change). Data in B and C are a mean of the data obtained with single-channel recording.

Voltage dependence of the opening and closing transitions

The voltage dependence of the gating of wt BK channels, and also presumably for the mutant BK\(_B\) channels because of their essentially identical voltage sensitivity to wt channels (see preceding section), reflects gating...
charge movement associated mainly with the voltage-dependent movement of the S4 voltage sensors and also a weaker voltage dependence associated with the opening/closing transitions (Díaz et al., 1998; Horrigan et al., 1999; Rothberg and Magleby, 2000; Horrigan and Aldrich, 2002; Ma et al., 2006). At very negative potentials the voltage dependence of the opening/closing transitions can be estimated directly because the S4 voltage sensors are held in their resting positions (Stefani et al., 1997; Horrigan et al., 1999; Horrigan and Aldrich, 2002). Fig. 2 A plots Po versus voltage for data obtained from patches with one or more BKβ channels at saturating (95 µM) Ca2+. The shallow part of the curve at voltages more negative than approximately −100 mV reflects the voltage dependence of the opening and closing transitions, as the S4 voltage sensors are held in their deactivated positions. The steeper part of the curve reflects mainly the voltage dependence of the movement of the S4 voltage sensors as well as the voltage dependence of the opening and closing transitions (Horrigan and Aldrich, 2002; Ma et al., 2006).

Fig. 2 (B and C) plots the mean open time and mean closed time versus voltage. Fitting the voltage dependence of the mean open and closed times at voltages more negative than −100 mV indicates a partial charge of −0.0994 ± 0.015 e0 for the closing transition (−257 mV per e-fold increase in closing rate) with a projected rate constant of 6,420 ± 680 s−1 at 0 mV (Fig. 2 B) and a partial charge of 0.237 ± 0.06 e0 for the opening transition (108 mV per e-fold increase in opening rate) with a projected rate constant of 3.87 ± 1.88 s−1 at 0 mV (Fig. 2 C). These estimates of partial charge are not significantly different from the estimates of −0.145 ± 0.007 e0 for the closing transitions (P > 0.1) and 0.22 ± 0.005 e0 for the opening transition (P > 0.7) obtained by Horrigan and Aldrich (2002) for wt BK channels with 70–100 µM Ca2+. Estimates of partial charge movement from Rothberg and Magleby (2000) for the C-O and
O-C transitions are also, within experimental variability, consistent with the aforementioned two estimates.

Dwell-time distributions for BKβ channels in saturating Ca^{2+}

Fig. 3 plots representative open and closed dwell-time distributions obtained from a BKβ channel at −70, −50, 50, and 70 mV with saturating 95 μM Ca^{2+}. For this channel and the three additional channels studied in detail, the open and closed distributions were typically described by the sums of two open exponential components and three to five closed exponential components, respectively, similar to wt BK channels for a similar number of analyzed intervals (McManus and Magleby, 1988; Rothberg and Magleby, 2000). Therefore, BKβ channels are predominantly gating in a minimum of two open and three to five closed states for each voltage.

Exploring the voltage-dependent gating mechanisms for BKβ channels using highly idealized constrained models

Scheme I presents a 50-state two-tiered model as a possible gating mechanism for a channel with one Ca^{2+} sensor and one voltage sensor per subunit (for review see Magleby, 2003), as is the case for the BKβ channel. Adding sufficient Ca^{2+} to saturate the Ca^{2+} bowl for the BKβ channel would then effectively drive the gating to

Figure 3. Open and closed dwell-time distributions for BKβ channel DM4 at the indicated voltages in saturating Ca^{2+}. Lines are mixtures of exponential components fitted to the dwell times. Open time histograms were described by one to two significant exponential components, and closed time histograms were described by two to five significant exponential components. The time constants and areas of the exponentials for the four studied channels are given in Tables S1 and S2. A moving bin mean of three consecutive bins was used for the data at negative potentials because of the small numbers of intervals at the low Po. Channel DM4 is presented in Figs. 3–7 as a representative channel. Similar conclusions were reached with channels DM1–DM3.
the right-most 10 states, giving the 10-state model indicated by Scheme II. Previous studies have shown that voltage and Ca$^{2+}$ activation of wt BK channels can be approximated by Scheme I and that voltage activation alone can be approximated by Scheme II (Cox et al., 1997; Horrigan and Aldrich, 1999, 2002; Rothberg and Magleby, 1999, 2000; Horrigan et al., 1999; Cui and Aldrich, 2000; Bao et al., 2002; Ma et al., 2006; for review see Magleby, 2003).

We now expand on Scheme II to examine the specific allosteric coupling and cooperative factors involved in the gating of BK$_{B}$ channels by voltage for the 10-state model induced by saturating Ca$^{2+}$. The models to be tested are indicated by Schemes III–V with the indicated constraints on the gating parameters. These idealized schemes are based on previous constrained models for various voltage-dependent channels (Marks and Jones, 1992; Ríos et al., 1993; McCormack et al., 1994) and also for wt BK channels (Cox et al., 1997; Horrigan and Aldrich, 1999, 2002; Horrigan et al., 1999; Ma et al., 2006). These schemes can also be considered as extensions of models for BK channels with a limited number of states with unconstrained rate constants (Rothberg and Magleby, 1998, 1999, 2000).

The gating parameter $A$ in these schemes is the forward rate constant for the activation of a single voltage sensor at 0 mV. $B$ is the backward rate constant for deactivation of a voltage sensor at 0 mV. The $4, 3, 2, \text{ and } 1$ for the forward activation and backward deactivation of voltage sensors indicate the number of voltage sensors available for activation or deactivation, respectively. $H$ and $K$ are the opening and closing rate constants when all voltage sensors are deactivated, and $H_F$ and $K_F$ are the rate constants to and from flicker closed states. Partial Scheme F is an additional tier of closed states that can be added below any of the above schemes to add a tier of brief flicker closed states that are entered from the open states.

$A, B, H, \text{ and } K$ have allowed voltage dependence, with the voltage dependence described by Rate($V$) = Rate(0) $\exp(Vq/kT)$, where $q$ is the effective charge movement associated with the transition. For an effective charge of 1.0 e$_{0}$, for $q$, $q/kT = 1/25.5 \text{ mV at } 23^\circ \text{C}$. $D$ and $E$ in Schemes IV and V are coupling factors for channel opening and closing, where each activated voltage sensor changes the opening rate $D$-fold and the closing rate $E$-fold. Thus, one to four activated voltage sensors change the opening rates by $D, D^2, D^3, \text{ and } D^4$ and the closing rates by $E, E^2, E^3, \text{ and } E^4$. $U$ and $W$ in Scheme V are cooperative factors for voltage sensor activation and deactivation, respectively. Each activated voltage sensor changes the activation rate of each of the deactivated voltage sensors $U$-fold, and each deactivated voltage sensor changes the deactivation rate of each of the activated voltage sensors $W$-fold. Therefore, one to three activated voltage sensors would increase the activation rate of the deactivated voltage sensors by $U, U^2, \text{ and } U^3$, and one to three deactivated voltage sensors would change the deactivation rate of the activated voltage sensors by $W, W^2, \text{ and } W^3$. Values of $D, E, U, \text{ and } W>1.0$ would increase transition rates, and values $<1.0$ would decrease transition rates.

Schemes III–V depict only a few of the many possible mechanisms that could be proposed for gating. Although it seems unlikely that gating would exactly follow such a systematic imposition of the effects of one to four activated voltage sensors on coupling and cooperativity, these highly constrained idealized models can serve as useful starting points for analysis. Notice that with the exception of $A$ and $B$, these parameters have different meanings than those in Horrigan and Aldrich (2002).

Because the gating of BK channels is consistent with microscopic reversibility (McManus and Magleby, 1989; Song and Magleby, 1994), the rate constants in Schemes III–V are further constrained so that the transitions around any of the 10 possible loops in these schemes are identical in the clockwise and counterclockwise directions (Colquhoun and Hawkes, 1995). Imposing microscopic reversibility requires the inclusion of $D$ and $E$ in

![Figure 4](https://example.com/figure4.png)

**Figure 4.** Comparison of the observed and predicted voltage dependence of Po for BK$_{B}$ channel DM4 on linear and log-linear coordinates for the indicated gating mechanisms with saturating Ca$^{2+}$. A: linear coordinates; B, log-linear coordinates. Saturating Ca$^{2+}$ superimpose over most of the voltage range and give a somewhat more accurate description of the data at negative voltages than the other schemes.
The most likely rate constants determined from fitting were then used with Scheme III to predict Po and the dwell-time distributions for comparison to the experimental data.

Scheme III approximates Po over limited voltage ranges, accounts for the voltage dependence of the open dwell times, and does not describe the closed dwell times. We first examined whether Scheme III, which has no coupling or cooperative factors, could describe the voltage-dependent gating of BK<sub>K</sub> channels. This was done by simultaneously fitting 2-D dwell-time distributions of adjacent open and closed intervals obtained at six to nine different voltages with Scheme III to obtain the values for the rate constants A, B, K, and H that maximized the probability that the single-channel data were drawn from the 2-D distributions predicted by Scheme III. The most likely rate constants determined from fitting were then used with Scheme III to predict Po and the dwell-time distributions for comparison to the experimental data.

Fig. 4 (A and B) presents linear and log-linear plots showing that Scheme III can approximate the large increases in Po with depolarization but gives a poor description of Po for negative voltages (dashed blue lines). Scheme III can describe the depolarization-induced right shift to longer open times in the open dwell-time distributions (Fig. 5, left, dashed blue lines). However, Scheme III could not describe the voltage dependence of the closed dwell-time histograms over the entire voltage range. The most likely parameters for Scheme III for channel DM4 are in Table S3, where
it can be seen that depolarization increases \( A \), the rate constant for voltage sensor activation, through \( q_H \) (0.0721 \( e_o \)), decreases \( B \), the rate of voltage sensor deactivation, through \( q_b \) (−0.100 \( e_o \)), increases the opening rate constant \( H \) through \( q_{\text{D}} \) (1.36 \( e_o \)), and decreases the closing rate constant \( K \) through \( q_k \) (−0.383 \( e_o \)). These most likely (in terms of the model) indirect estimates of partial charge for Scheme III place the majority of the voltage dependence in the opening and closing transitions rather than in voltage sensor activation and deactivation, the opposite of what is observed with more direct measurements (Horrigan and Aldrich, 1999; Horrigan et al., 1999) or more likely models (see following paragraph and Rothberg and Magleby, 2000). The complete inability of Scheme III to account for the closed dwell-time distributions (Fig. 5, right, dashed blue lines) requires that this scheme be rejected and suggests that additional factors are involved in the gating of BKB channels.

Schemes IV and V give progressively improved descriptions of the single-channel kinetics

We next examined whether Scheme IV, with the added allosteric parameters \( D \) and \( E \) to couple the opening and closing transitions to the voltage sensor movement, could describe the single-channel kinetics. Scheme IV approximated the increase in Po with depolarization (Fig. 4, red lines) and described the right shift in the open dwell-time distributions with depolarization (Fig. 5, left, red lines). Scheme IV gave a greatly improved description of the closed distributions compared with Scheme III, but there were still some marked differences between the observed and predicted distributions (Fig. 5, right, red lines).

We next examined whether Scheme V, which is like Scheme IV but with allowed cooperativity among the voltage sensors through the parameters \( U \) and \( W \), would improve the description of the data over Scheme IV. Scheme V gave a somewhat improved description of the effect of depolarization on Po (Fig. 4, green lines often masked by black lines) and described the effect of depolarization on the open dwell-time distributions (Fig. 5, left, green lines often masked by black lines).

Scheme V also gave further improved descriptions of the closed dwell-time distributions over Scheme IV, capturing all the major features (Fig. 5, right, green lines often masked by black lines).

Adding flicker closed states improves the description of the single-channel kinetics

Rothberg and Magleby (1998, 1999) found for simplified gating mechanisms for wt BK channels that the addition of a brief closed state to each open state to generate additional brief closed intervals (flickers) improved the ability of the models to describe the experimental data. Consequently, we examined whether the addition of partial Scheme F to Schemes IV and V to add a flicker state to each open state would improve the description of the data. The addition of flicker states to Scheme IV to form Scheme IV\(_F\) had little effect on the descriptions of Po and the open distributions but gave improved descriptions of the closed dwell times except for very brief intervals at negative potentials (compare blue continuous lines with the red lines in Figs. 4 and 5, right). The addition of flicker states to Scheme V to form Scheme V\(_F\) gave essentially the same excellent visual description of the data as Scheme V (Figs. 4 and 5, black lines superimposing the green lines). Thus, Schemes \( V_F \) and \( V_{\text{FF}} \), both of which have coupling and cooperativity, describe the voltage dependence of Po and the single-channel kinetics.

Ranking the different gating mechanisms

Table II ranks the various schemes for the four different examined channels on the basis of likelihood using the SC, which applies a heavy penalty for additional free parameters (see Materials and methods). For channels DM1, DM2, and DM3, the ranking of the various schemes was, from lowest to highest, Schemes III, IV, IV\(_F\), V, and V\(_F\). The rankings were the same for channel DM4 except that the rankings of Schemes IV\(_F\) and V were reversed. The likelihood ratio test (see Materials and methods) gave the same rankings as the SC and also indicated that each of the higher ranked models were significantly better than the lower ranked models (\( P < 0.001; \text{Table S4} \)). The top-ranked Scheme V\(_F\) had both
coupling \((D\) and \(E)\) and cooperative factors \((U\) and \(W)\) as well as flicker closed states.

Also listed in Table II are the normalized likelihoods per interval pair for each of the schemes and channels expressed as a ratio to the top-ranked Scheme \(V_F\) (see Materials and methods). Averaging the normalized likelihood ratios in Table II for the four channels indicated that Schemes \(III, IV, IV_F, \) and \(V\) were 0.270, 0.952, 0.977, and 0.997 as likely, respectively, per interval pair as the top-ranked Scheme \(V_F\).

Predicting the 2-D dwell-time distributions and single-channel currents

Fig. 6 shows that the top-ranked Scheme \(V_F\) can approximate the description of the 2-D dwell-time distributions. These distributions include the information in the 1-D distributions, as in Fig. 5, as well as correlation information that helps define the connections among states (Fredkin et al., 1985; Magleby and Song, 1992; Gil et al., 2001). Fig. 6 A presents a 2-D dwell-time distribution of experimental data for gating at 50 mV. The distribution plots the square root of the number of observed adjacent interval pairs in each bin on the \(z\) axis versus the log of the mean open-(\(y\) axis) and closed-(\(x\) axis)-interval durations for that bin. The interpretation of such plots has been presented previously in detail (Magleby and Song, 1992; Rothberg and Magleby, 1998) so will only be described here in brief. Fig. 6 A indicates that the most frequently observed interval pairs for BKb channels at 50 mV with saturating \(\text{Ca}^{2+}\) are longer openings adjacent to briefer closings, as indicated by the prominent peak at \(-0.5\) (0.3 ms) on the \(y\) axis and \(-1.5\) (0.03 ms) on the \(x\) axis. Three additional frequently observed adjacent interval pairs are present in Fig. 6: longer openings adjacent to longer closings (bump in right back quadrant of plot), shorter openings adjacent to longer closings (bump in right front quadrant), and briefer openings adjacent to briefer closings (bump in left front quadrant). A visual comparison of the experimental distribution in Fig. 6 A to the predicted distribution in Fig. 6 B shows that Scheme \(V\) captures the major features of the 2-D dwell-time distribution.

Fig. 7 presents simulated single-channel currents for Scheme \(V\) for comparison with the experimental currents in Fig. 1 A. The major features of the single-channel currents are captured by Scheme \(V\) over the wide range of voltages examined.

Gating parameters for Schemes \(IV, IV_F, V, \) and \(V_F\)

Table III presents the estimated gating parameters for Schemes \(IV\) through \(V_F\) as the mean ± SEM of the estimates for each of the four examined channels. Table S3 presents the parameters for channel DM4 for Schemes \(III\) through \(V_F\). In interpreting the parameters, it needs to be kept in mind that the examined schemes are
idealized by being highly constrained (see schemes) with strict mathematical relationships determining the coupling and cooperative (when included) parameters. Because it is unlikely that a protein as complex as the BK channel would gate in the highly constrained manner defining these models, both the models and estimated parameters should be viewed as tools toward understanding gating, rather than as actual gating mechanisms. The goal when examining the various models and parameters in the following sections is not to make fine distinctions among the models but to draw general conclusions that may apply to the underlying gating mechanism.

Estimates of partial charge movement
For the top-ranked Scheme VF, the partial charge estimates for BK channels of 2.3 ± 0.6 e_o (Rothberg and Magleby, 2000) and 2.62 (Ma et al., 2006). Thus, to a first approximation, eliminating both the RCK1 Ca^{2+} sensor and the Mg^{2+} sensor through mutations to obtain BK channels does not change the effective gating charge of BK channels even though the data were obtained.

The effective charge movement for gating with each scheme was obtained by summing up the partial charges in the gating mechanisms for the movement of the voltage sensors (4 × q_h + 4 × −q_b) plus the partial charge movement associated with the opening and closing transitions (q_H + −q_K). For Scheme VF, the total effective charge movement for the four examined channels was 2.26 ± 0.17 e_o (Table III), and the mean value for the four different gating schemes for the four channels was 2.52 ± 0.18 e_o. These values obtained from the voltage dependence of the various parameters in the kinetic schemes are consistent with the total effective charge movement from Table I of 2.29 ± 0.20 e_o determined from the slope of P_o versus voltage. Fixing either one of the partial charge estimates for a single rate constant and then refitting indicated that changing one of the partial charges associated with a single rate constant (up to twofold with preservation of the sign) typically had small effects on the likelihoods as long as the total gating charge was preserved. This indicates that it is the total effective charge movement that is the most critical factor in the voltage dependence, as might be expected.

The total effective charge movements estimated for BK channels are also consistent with values reported for wt BK channels. The effective charge movement for Scheme IV for the open to closed transition, q_h = −0.206 ± 0.077 e_o, is consistent with those determined for wt BK channels of 2.3 ± 0.6 e_o (Rothberg and Magleby, 2000) and 2.62 (Ma et al., 2006). Thus, to a first approximation, eliminating both the RCK1 Ca^{2+} sensor and the Mg^{2+} sensor through mutations to obtain BK channels does not change the effective gating charge of BK channels even though the data were obtained.

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### Table III

Gating parameters determined from four BK channels as mean ± SEM

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Scheme IV</th>
<th>Scheme IVF</th>
<th>Scheme V</th>
<th>Scheme VF</th>
</tr>
</thead>
<tbody>
<tr>
<td>A (s⁻¹)</td>
<td>369 ± 163</td>
<td>384 ± 159</td>
<td>240 ± 136</td>
<td>397 ± 197</td>
</tr>
<tr>
<td>q_h (e_o)</td>
<td>0.470 ± 0.075</td>
<td>0.290 ± 0.075</td>
<td>0.355 ± 0.057</td>
<td>0.247 ± 0.063</td>
</tr>
<tr>
<td>B (s⁻¹)</td>
<td>752 ± 215</td>
<td>1,090 ± 240</td>
<td>2,570 ± 1,190</td>
<td>1,700 ± 445</td>
</tr>
<tr>
<td>q_b (e_o)</td>
<td>−0.156 ± 0.090</td>
<td>−0.261 ± 0.074</td>
<td>−0.106 ± 0.053</td>
<td>−0.206 ± 0.077</td>
</tr>
<tr>
<td>H (s⁻¹)</td>
<td>0.310 ± 0.196</td>
<td>0.824 ± 0.760</td>
<td>1.19 ± 0.569</td>
<td>1.23 ± 0.864</td>
</tr>
<tr>
<td>q_b (e_o)</td>
<td>0.197 ± 0.130</td>
<td>0.316 ± 0.064</td>
<td>0.116 ± 0.067</td>
<td>0.150 ± 0.090</td>
</tr>
<tr>
<td>K (s⁻¹)</td>
<td>4,540 ± 1,250</td>
<td>5,030 ± 1,960</td>
<td>3,450 ± 1,160</td>
<td>2,030 ± 587</td>
</tr>
<tr>
<td>q_h (e_o)</td>
<td>−0.217 ± 0.091</td>
<td>−0.218 ± 0.032</td>
<td>−0.225 ± 0.103</td>
<td>−0.294 ± 0.142</td>
</tr>
<tr>
<td>D</td>
<td>22.9 ± 3.98</td>
<td>28.3 ± 2.15</td>
<td>17.9 ± 1.90</td>
<td>17.4 ± 2.20</td>
</tr>
<tr>
<td>E</td>
<td>0.997 ± 0.080</td>
<td>0.990 ± 0.097</td>
<td>1.37 ± 0.06</td>
<td>1.48 ± 0.061</td>
</tr>
<tr>
<td>U</td>
<td>4.13 ± 1.62</td>
<td>5.02 ± 3.24</td>
<td>1.31 ± 0.50</td>
<td>1.34 ± 0.39</td>
</tr>
<tr>
<td>W</td>
<td>621 ± 88.6</td>
<td>603 ± 276</td>
<td>21,200 ± 3,070</td>
<td>35,600 ± 19,600</td>
</tr>
<tr>
<td>H_b (s⁻¹)</td>
<td>21,200 ± 3,070</td>
<td>35,600 ± 19,600</td>
<td>621 ± 88.6</td>
<td>603 ± 276</td>
</tr>
<tr>
<td>K_b (s⁻¹)</td>
<td>2.92 ± 0.59</td>
<td>2.74 ± 0.07</td>
<td>2.18 ± 0.15</td>
<td>2.26 ± 0.17</td>
</tr>
</tbody>
</table>

D, E, U, and W are without units. q_h = net gating charge = 4q_h − 4q_b + q_H − q_K. The gating parameters are absent in the indicated kinetic schemes (blank cells).
in saturating Ca\textsuperscript{2+} for the Ca\textsuperscript{2+} bowl. This conclusion is consistent with previous findings that the voltage sensors and Ca\textsuperscript{2+} sensors of BK channels function relatively independently of one another (Cui and Aldrich, 2000; Rothberg and Magleby, 2000; Horrigan and Aldrich, 2002).

### Coupling of the voltage sensors to channel opening and closing through D and E

For Schemes IV, IVF, V, and VF, each activated voltage sensor changes the C→O opening rate D\textsuperscript{fold} and the O→C closing rate E\textsuperscript{fold}. Values of D and E >1.0 would increase the transition rates, and values <1.0 would decrease them. For Schemes IV and IVF, the voltage sensors are independent of one another, whereas for Schemes V and VF, cooperative interactions through U and W are allowed among the voltage sensors. For Schemes IV, IVF, V, and VF, estimates of the coupling factor D were large, ranging from 17.4 to 28.3 (Table III), with a mean value for the four schemes of 21.6 ± 2.5. These estimates of D were significantly different from 1.0 (P < 0.001). A value of D of 21.6 would accelerate the opening rate 21.6-, 467-, 10,078-, and 217,678-fold for one, two, three, and four voltage sensors activated, respectively.

E for Schemes IV and IVF was ~0.99 ± 0.1 and not significantly different from 1.0, whereas E for Schemes V and VF was ~1.4 ± 0.1 and was significantly different from 1.0 (P < 0.05). An E of ~0.99 would have a negligible effect on the channel closing rates, whereas an E of 1.4 would accelerate the closing rate 1.4-, 2.0-, 2.7-, and 3.8-fold for one, two, three, and four voltage sensors activated, respectively. Adding flicker closed states to Schemes IV and V to obtain Schemes IVU and IVF had little effect on estimates of D or E (Table III).

At first it may seem paradoxical that voltage sensor activation may increase closing rates. However, the acceleration of the closing rate by E for Schemes V and VF is small compared with the much larger effects of D on accelerating the opening rates (discussed above). Furthermore, the relative stability of the open and closed states depends on all of the rate constants in the kinetic scheme, with the rate constants being affected in a complex way by the various parameters (see Scheme V) and their voltage dependence. The net result is that voltage sensor activation does stabilize the open states, as measured by equilibrium occupancy. For example, for channel DM4 at 60 mV, the equilibrium occupancy of the open states with from zero to four voltage sensors activated is 0.000053, 0.000354, 0.0029, 0.037, and 0.63, respectively.

As discussed above and shown in Table III, our analysis determines separately the coupling of voltage sensor activation to both the opening C→O and closing O→C rates. The effect of voltage sensor activation on the C→O equilibrium is given by D\textsubscript{HA} = D/E, where D\textsubscript{HA}, as defined by Horrigan and Aldrich (2002), indicates that the activation of each voltage sensor changes the C↔O equilibrium D\textsubscript{HA}\textsuperscript{fold}. Calculating D\textsubscript{HA} from the values of D and E in Table III gives estimates of D\textsubscript{HA} of 23.0 and 28.6 for Schemes IV and IVF, which have independent voltage sensors. When the SEMs of D and E in Table III are taken into account, these estimates are not different from the estimate for D\textsubscript{HA} of 23.9 from Ma et al. (2006), which was also calculated assuming independent voltage sensors.

For Schemes V and VF, which allow cooperativity among the voltage sensors, estimates of D\textsubscript{HA} from the values of D and E in Table III were 13.1 for Scheme V and 11.7 for Scheme VF. Thus, allowed voltage sensor cooperativity decreases the estimated magnitude of the coupling between voltage sensor activation and the C↔O equilibrium.

Independent of whether the schemes had independent voltage sensors (Schemes IV and IVF) or cooperativity among voltage sensors (Schemes V and VF), voltage sensor activation of the channel was mainly through coupling factor D accelerating the opening rates with minimal effect of coupling factor E on the closing rates.

### Possible cooperativity among the voltage sensors through U and W

The estimates of cooperativity among the voltage sensors for Schemes V and VF indicated that each activated voltage sensor accelerates the activation rate of the de-activated voltage sensors ~4.6-fold and increases the deactivation rate of each activated voltage sensors ~1.3-fold (mean of the values of U and W obtained from Schemes V and VF in Table III). These estimates of U and W were not significantly different from 1.0 (P > 0.1) because of large SEMs. Nevertheless, allowing U and W cooperativity (compare Scheme V with Scheme IV and Scheme VF with Scheme IVF) led to significantly higher rankings for all four channels (P < 0.001; Table II and Table S4), which is consistent with possible cooperativity among voltage sensors for the examined models. In terms of Schemes V and VF, one, two, and three activated voltage sensors would increase the activation of the deactivated voltage sensors 4.6-, 21.2-, and 97.3-fold, respectively, through U (based on the mean value of U for Schemes V and VF), and one, two, and three deactivated voltage sensors would increase the deactivation rate of the activated sensors 1.3-, 1.7-, and 2.2-fold through W (based on the mean value of W for Schemes V and VF). In terms of the models, cooperativity among voltage sensors greatly accelerates the activation of voltage sensors while having much less of an effect on their deactivation.

### Constraining parameters indicates that estimates of D, E, U, and W are robust

The gating parameters in the kinetic schemes were typically free, with their values determined by the maximum
likelihood fitting process. We also examined whether fixing some of the parameters to values determined independently would lead to similar conclusions about coupling and cooperativity as those obtained with free parameters. Two examples are presented in Table IV for Schemes IV and V. Fixing \( q_a, q_b, q_H, \) and \( q_K \) to the values in Horrigan and Aldrich (1999) and then fitting gave coupling and cooperativity factors for Schemes IV and V that were not significantly different (\( P > 0.4 \)) from those determined when the parameters were free (Table IV). Fixing \( H, K, q_H, \) and \( q_K \) to the values obtained in Fig. 2 also gave coupling and cooperativity factors that were not significantly different (\( P > 0.09 \)) for each factor from those determined when the parameters were not fixed (Table IV). No significance difference in the coupling and cooperativity factors for fixed versus free partial charges were also found (not depicted) when using fixed partial charges estimates from Rothberg and Magleby (2000) and from Horrigan and Aldrich (2002).

Thus, fitting with some parameters fixed by independent estimates supports the conclusions from the free parameter fitting in the previous sections that coupling occurs mainly through \( D \) rather than \( E \) and that possible cooperativity occurs mainly through \( U \) and not \( W \).

**Comparison of models with cooperativity among voltage sensors to models with free parameters for each opening and closing rate**

The results in the previous sections show that allowing cooperativity among the voltage sensors (Schemes V and \( V_F \)) can improve the description of the gating. Such an observation does not, of course, establish cooperativity but may simply reflect that additional free parameters can improve the description of the data or that the highly constrained idealized models force a distortion of some of the examined parameters from the true underlying parameters. Thus, the question arises whether relaxing constraints on factors other than cooperativity might also improve the description of the data.

To explore this possibility, we examined a new scheme in which the constraints on the strict coupling between voltage sensor activation and the opening/closing transitions were removed. To develop this new scheme, referred to as Scheme IV-free, \( E, E^2, E^3, D, D^2, D^3, \) and \( D^4 \) in Scheme IV were replaced with free rate constants \( E_0, E_1, E_2, E_3, D_0, D_1, D_2, \) and \( D_3 \), respectively, together with appropriate changes in the parameters for the O–O transitions to maintain microscopic reversibility. All opening rate constants in Scheme IV-free have the same partial charge movement incorporated through the voltage dependence of \( K, \) and all closing rate constants have the same partial charge movement incorporated through the voltage dependence of \( H. \) Scheme IV-free retains the independent voltage sensor activation found in Scheme IV. Scheme IV-free was then compared with Scheme V, which has cooperativity among the voltage sensors. Scheme IV-free ranked below Scheme V for all channels (Table S5, top pairing). Therefore, for these two 10-state schemes, a model with cooperativity among voltage sensors is preferred over a model with free rate constants for the opening and closing transitions.

For 15-state models, Scheme IV\(_F\)-free (Scheme IV\(_F\)-free with added flickers) ranked below Scheme \( V_F \) for two channels and above Scheme \( V_F \) for the other two channels (Table S5, middle pairing). Thus, for models with flickers, the rankings give no preference between models with unconstrained coupling or with cooperativity among voltage sensors. For both Scheme IV-free and Scheme IV\(_F\)-free, the opening rates still increased with a power approximated by the number of activated voltage sensors, with the free coupling typically making minor adjustments in the opening rates compared with the constrained models. Thus, the basic features of the gating were preserved.

Interestingly, starting with Scheme IV\(_F\)-free and also allowing cooperativity among voltage sensors to obtain Scheme \( V_F \)-free allowed Scheme \( V_F \)-free to rank above Scheme IV\(_F\)-free for all four channels (Table S5, bottom
pairing), consistent with, but not establishing, cooperativity among voltage sensors for the examined models.

The gating with free coupling between voltage sensors and the opening/closing transitions was consistent with the major conclusions from the previous sections: voltage sensor activation still increased Po mainly through increases in the opening rates, with limited effects on the closing rate constants; and models with allowed cooperativity among voltage sensors ranked above the same models without such cooperativity. A difficulty with relaxed constraints on the coupling is that the resulting extra free parameters can lead to several of the free parameters being poorly defined, rendering the models of limited use for structure/function studies. Schemes V and VF with fewer free parameters already provide an adequate description of the data and should be suitable for such studies.

**DISCUSSION**

In this study, we examine possible allosteric coupling and cooperative factors involved in the voltage-dependent gating of a simplified BK channel, BKδ, with only one Ca2+ binding site (the Ca2+ bowl) per subunit. The Ca2+ bowl was then saturated with Ca2+ to drive the gating into the 10-state two-tiered model in Scheme II. The simplified BKδ channels with saturating Ca2+ were used to increase the activity sufficiently so that single-channel data could be collected over a wide range of Po and voltage. Single-channel data provided a means to test the ability of the various models to account for the detailed gating kinetics and also to facilitate the estimation of rate constants rather than equilibrium constants. The results of our study indicate that the steady-state voltage-dependent single-channel kinetics of BKδ channels is not described by Scheme III, can be approximated by Schemes IV and IVF, and are well described by Schemes V and VF.

Scheme III, a highly constrained MWC-like model (Monod et al., 1965; Fersht, 1985) with voltage sensors rather than ligand sensors and with no allosteric coupling between voltage sensors and the opening and closing transitions rates, could, rather surprisingly, provide a description of the voltage dependence of the open distributions and could also approximate Po over limited ranges of voltage. However, Scheme III did not even come close to approximating the voltage dependence of the closed time distributions (Figs. 4 and 5, dashed blue lines). Clearly, an MWC-like model without coupling of the voltage sensors to the opening and closing transitions is inconsistent with the single-channel kinetics. (These findings with Scheme III also illustrate that the ability to approximate Po on a linear plot does not necessarily provide a critical test of a model. Such tests must explore wide ranges of voltage, including very low Po’s.)

Allowing allosteric coupling between voltage sensors and channel opening and closing (Schemes IV and IVF) based on highly constrained and idealized allosteric models considered previously (Marks and Jones, 1992; Ríos et al., 1993; McCormack et al., 1994; Horrigan et al., 1999; Horrigan and Aldrich, 2002) gave greatly improved descriptions of the gating. In these models, we used separate allosteric factors for coupling voltage sensor movement to the opening (D) and closing (E) transitions rather than an equilibrium coupling factor. The highly constrained Scheme IV captured the major features of the voltage dependence of Po and the single channel data, but with some noticeable errors in Po at very negative potentials and in the closed dwell-time distribution (Figs. 4 and 5). The constraints in Scheme IV reduced the number of gating parameters to 10 (the coupling factors D and E and the rate constants A, B, K, and H and their associated voltage dependence). Without any constraints there would be 48 free parameters; 26 rate constants with two parameters each to define the rate constants at 0 mV and their voltage dependence, minus one parameter in each of the four loops to constrain microscopic reversibility. The rather amazing finding is that the highly constrained Scheme IV with only 10 free parameters compared with approximately five times that number if all were free could approximate the voltage dependence of Po and capture the major features of the single-channel kinetics, as revealed through the open and closed dwell-time distributions.

For Scheme IV, the allosteric factor D increased the opening rate an additional 22.9-fold for each activated voltage sensor (Table III). One to four activated voltage sensors would then accelerate the opening rate 22.9-, 524-, 12,000-, and 275,000-fold, respectively. The allosteric coupling factor E for channel closing was ~1.0, so there would be little effect of voltage sensors on the closing rates. Thus, changes in the open–close equilibrium coupling factor $D_{\text{HA}}$ for Scheme IV and those by Horrigan (2002) would arise through changes in the opening rate. Consequently, our allosteric coupling factor D for opening of 22.9 ± 4.0 for Scheme IV can be compared directly with, and is not significantly different from, estimates of the equilibrium allosteric coupling factor $D_{\text{HA}}$, which ranged from 23.9 to 25 (Horrigan and Aldrich, 2002; Ma et al., 2006; Horrigan and Ma, 2008). Estimates of $D_{\text{HA}}$ for Scheme IV and those by Horrigan and co-workers were determined assuming no cooperative interactions among voltage sensors.

Allowing cooperativity in activation of voltage sensors with Scheme V further improved the description of the data so that the predictions with Scheme V essentially superimposed both the voltage dependence of the experimentally observed Po and also the dwell-time histograms (Figs. 4 and 5). For Scheme V, each activated voltage sensor increased the activation rate of
the remaining voltage sensors $4.1 \pm 1.6$-fold ($U$) with little effect ($1.3 \pm 0.5$) on the deactivation rate ($W$). With this allowed cooperativity among the voltage sensors, estimates of $D$ were decreased from 23 to 17.5, and estimates of $E$ were increased from 1.0 to 1.4, changing $D_{IA}$ from 23 to 12.5. Thus, if cooperativity among voltage sensors is present but not included in models, the models can compensate by changing the coupling factors to increase the $D_{IA}$. Thus, voltage sensor cooperativity, if present, could masquerade as an increased coupling factor if voltage sensor cooperativity is not included in the model.

Consistent with the possibility of cooperativity in activation of voltage sensors in BK channels, Horrigan and Aldrich (2002) cleverly deduced a possible calcium-dependent cooperativity in voltage-sensor movement for wt BK channels from limiting slope analysis of $P_o$ (their Fig. 12). If the structure and position of each voltage sensor domain (S1–S4) in BK channels is similar to that in Kv1.2 channels, the S4 segments of the voltage sensors would be separated from one another and unlikely to interact directly (Long et al., 2005a,b; Horn, 2009). Nevertheless, the S4–S5 linker of each voltage sensor in Kv1.2 runs underneath a neighboring subunit to connect to S5, allowing intersubunit interactions (Tombola et al., 2006). In addition, retrograde action on the voltage sensors is possible through possible cooperative changes in tension on the S4–S5 linkers. For BK channels, the large intracellular gating ring may also interact with intracellular parts of the voltage sensor and the S4–S5 linker, providing more points for interactions (Horrigan and Ma, 2008; Yang et al., 2008).

The possible voltage sensor cooperativity observed by Horrigan and Aldrich (2002) was Ca$^{2+}$-dependent, requiring saturating Ca$^{2+}$ for the two high affinity Ca$^{2+}$ sites per subunit on the wt channels in their experiments. In addition, the cooperativity we observed was in saturating Ca$^{2+}$ for the one high affinity Ca$^{2+}$ site per subunit for the BK$_B$ channels in our experiments, implicating an activated gating ring in the cooperativity among voltage sensors. Previous studies suggest that Ca$^{2+}$ expands the gating ring, increasing Po by perhaps pulling on the S6 gates through gating ring–S6 linkers (Jiang et al., 2002; Niu et al., 2004; Dong et al., 2005; Ye et al., 2006; Lingle, 2007). Therefore, Ca$^{2+}$-dependent cooperativity in voltage sensor activation for BK channels may be associated with or require an expanded gating ring that interacts with the voltage sensors/S4–S5 linkers, allowing cooperativity in some manner, or instead, the expanded gating ring may apply increased opening tension on the RCK1-S6 linkers, which could facilitate the cooperative movement of the voltage sensors in some manner.

As mentioned previously, our observation that allowing voltage sensor cooperativity leads to higher ranking models is consistent with, but does not establish, voltage sensor cooperativity. In principle, direct measurement of gating currents could reveal voltage sensor cooperativity. Scheme IV (without cooperativity among voltage sensors) with the parameters in Table III predicts that gating currents should be at maximum immediately after the voltage step and then decay thereafter, whereas Scheme V with cooperativity among voltage sensors and the parameters in Table III predicts a delay to peak gating currents of $\sim 35$ µs followed by a decay (determined by tabulating partial charge movement during simulation of single-channel gating). The gating currents for wt BK channels in Horrigan and Aldrich (1999) show a delay to peak, but this delay arises from the filtering associated with the experimentation, as Horrigan and Aldrich (1999) show in their Fig. 9.

Alternatively, it is possible that the mutated BK channel and $95 \text{ µM Ca}^{2+}$ used in our analysis induces cooperativity among voltage sensors that would be absent in the Horrigan and Aldrich (1999) measurements of gating currents in wt BK channels performed in 0 Ca$^{2+}$. Consistent with this possibility, the study of Horrigan and Aldrich (2002) suggests possible cooperativity in voltage sensor activation for wt BK channels gating in Ca$^{2+}$. This cooperativity was based on estimates of open-channel charge movement, raising the possibility that voltage sensor activation may be cooperative only when channels are open. If this is the case, the absence of a delay in the ON gating current would not exclude cooperativity interactions. Gating current experiments on BK$_B$ channels in $95 \text{ µM Ca}^{2+}$ should allow resolution of the question of possible cooperativity among voltage sensor activation under the conditions of our experiments. Depending on the findings, the idealized models could be modified to be consistent with the observed gating currents and then retested.

BK channels differ from Shaker Kv channels in that BK channels can open with zero to four voltage sensors activated (Stefani et al., 1997; Horrigan and Aldrich, 1999, 2002), as depicted in Schemes I–V. In contrast, Shaker Kv channels typically open after all four voltage sensors are activated (Zagotta et al., 1994; Schoppa and Sigworth, 1998; Gagnon and Bezanilla, 2009). Possible cooperativity among voltage sensors in Shaker channels, if present, is probably not pronounced, with reports of a small negative (Zagotta et al., 1994), a small positive (Schoppa and Sigworth, 1998), or negligible (Gagnon and Bezanilla, 2009; Horn, 2009) cooperativity, depending on the specific models and experiments. Cui et al. (2009) argue that similar basic mechanisms in voltage-dependent gating may apply to both BK and Kv channels but that unique structural features in BK channels may give rise to some differences.

Previous studies on BK channels have suggested the presence of flicker (brief duration) closed states (Rothberg and Magleby, 1998, 1999). Consistent with this finding,
the addition of flicker closed states to the constrained models to obtain Schemes IVF and VF significantly improved the description of the data. Such flicker closed states may arise from instability in the selectivity filter (Piskorowski and Aldrich, 2006; Schroeder and Hansen, 2007, 2008). It should be noted that the physical basis of the actual gate in BK channels is not clear (Piskorowski and Aldrich, 2006; Wilkens and Aldrich, 2006; Cui et al., 2009; Wu et al., 2009). Although the flicker states in Schemes IVF and VF were add-on states with flicker closing after opening, flicker states interposed between the closed and open states are also consistent with gating of BK channels (Rothberg and Magleby, 1999). Consequently, we cannot exclude that the flicker closed states are interposed between the closed and open states. Acetylcholine receptor channels also have flicker closed states (referred to as flipped or primed states) interposed between the closed and open states (Lape et al., 2008; Mukhtasimova et al., 2009).

In our analysis, the assumption was made that saturating the Ca\textsuperscript{2+} bowl on the BK\textsubscript{6} channel with high Ca\textsuperscript{2+} would drive the gating into the right-most 10 states, as in Scheme II. In practice, no matter how high the free Ca\textsuperscript{2+}, Ca\textsuperscript{2+} would still dissociate from the binding sites and then, assuming an on rate of 3 \times 10\textsuperscript{8} M\textsuperscript{-1} s\textsuperscript{-1} (Fersht, 1985), rebind after, on average, \sim \text{30 \mu s} for 100 \mu M Ca\textsuperscript{2+}. These brief unbindings should have minimal effects on the gating. To test this assumption, the data that were simultaneously fit for channel DM4 were also simultaneously fit with the 50-state Scheme I with the constraints of Scheme IV for the voltage-dependent gating. The Ca\textsuperscript{2+} on rate was fixed at 3 \times 10\textsuperscript{8} M\textsuperscript{-1} s\textsuperscript{-1}, and the Ca\textsuperscript{2+}i was fixed at 95 \mu M. The Ca\textsuperscript{2+} off rate determined by fitting was \sim 418/s. Typically, \sim 95\% of the state occupancy was in the right-most 10 states in Scheme 1, with only \sim 5\% in the 10 states immediately to the left of the right-most states and <0.1\% in the states further to the left. Estimates of the coupling and cooperative factors were little affected by allowing Ca\textsuperscript{2+} to unbind and rebind. Consequently, as a first approximation, the assumption that the gating is confined to the right-most 10 states appears suitable for the questions being addressed in our study.

If it is assumed that the actual underlying gating mechanism of BK\textsubscript{6} channels in saturating Ca\textsuperscript{2+} is generally consistent with Schemes IV, IV\textsubscript{F}, V, and V\textsubscript{F}, what does this tell us about mechanism? Consider Scheme IV, in which the coupling factor for \textit{D} was \sim 25 and the coupling factor for \textit{E} was \sim 1 (Table III). In terms of the examined highly constrained idealized models, these values indicate that the opening rate increases \textit{D}fold with each additional activated voltage sensor, whereas the closing rate remains relatively constant, independent of voltage sensor position. This suggests, in terms of the models, that the energy barrier for channel opening decreases with each additional activated voltage sensor, whereas the energy barrier for channel closing is little altered by voltage sensor movement. Where are these energy barriers? BK channels, like most channels, are bistable (typically open or closed), such that the time spent in transitioning between open and closed states is insignificant compared with the total time spent in the open and closed states. Bistable gating would be consistent with latch (or spring loaded) mechanisms forming the energy barriers to stabilize the closed and open states (Niu et al., 2004; Kahlig et al., 2006; Purohit and Auerbach, 2007; Wu et al., 2009).

BK channels can gate in the absence of Ca\textsuperscript{2+} and at very negative potentials where the voltage sensors are held in the deactivated position (Horrigan and Aldrich, 2002). Thus, thermal energy is sufficient to disrupt the closed latch and move the gate over to the open latch, even when no voltage or Ca\textsuperscript{2+} sensors are activated. In terms of Schemes IV and V, activated voltage sensors could then speed up the opening by reducing the strength of the closed latches or by applying a force to help pull the gates off the closed latches so that less thermal energy would be needed to disrupt the closed latches. In contrast (in terms of these specific schemes), activated voltage sensors would have little effect on the strength of the open latches or the forces acting to close open gates.

The properties of gating imposed by Schemes IV and V on BK channels have some features in common with a standard toggle switch. Both are bistable processes. For the toggle switch, a bistable spring mechanism holds the contacts either open or closed. For the BK channel, a bistable mechanism (springs and/or latches?) holds the gates either open or closed. For both of these switching devices, the time spent in transition between the two bistable states is insignificant compared with the time spent in the states. For the toggle switch, the absolute magnitudes of the (finger) forces required to either open or close the switch are typically identical. For the BK channel, the effective amount of energy required to open a channel at low P0’s can be orders of magnitude greater than the amount of energy required to close the same channel. Depolarization (and Ca\textsuperscript{2+}) then decreases the force required to open the channel while having much less of an effect on the force required to close the channel; at intermediate P0’s, the opening and closing forces can be about the same (like a toggle switch), whereas at very high P0’s, the opening force can be less than the closing force. Thus, BK channels can be viewed as a toggle switch with differential switching forces, depending on the conditions.

It is unlikely that a protein as complex as the BK or BK\textsubscript{6} channel would gate with the exact constraints imposed by the examined idealized gating mechanisms, and previous studies suggest some deviations from the constraints imposed by these schemes (Horrigan et al., 1999; Rothberg and Magleby, 2000; Horrigan and...
Consequently, the gating schemes tested in this study are, at best, approximations to the underlying gating mechanism. Nevertheless, the examined gating mechanisms are consistent with the quaternary structure of BK channels, the top-rated gating mechanisms approximate the voltage dependence of the steady-state single-channel gating kinetics over a 10,000-fold range in Po, and there is reasonable agreement between many of the gating parameters estimated in this study when compared with estimates from previous studies obtained with different experimental approaches (Rothberg and Magleby, 2000; Horrigan and Aldrich, 2002; Ma et al., 2006; Horrigan and Ma, 2008).

One advantage of the constrained models is that the number of free parameters is greatly reduced compared with models without constraints. This facilitates both estimation of the parameters and also comparison of parameters obtained under different experimental conditions or for structurally modified channels. A further advantage of constrained models is that they augment thinking in terms of underlying gating mechanism. A constrained model defines the gating for an idealized mechanism. To the extent that the gating deviates from the idealized mechanism, then this suggests additional aspects of gating that need to be included. These additional aspects can then be included and the whole process repeated iteratively until the developed gating mechanism can account for all aspects of the data. Gating would then be defined in terms of idealized models and deviations from those models.

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